

# RF Broadband Matching for 5G Probe Card without Using VNA

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# RF Broadband Matching for 5G Probe Card without Using VNA

- RF Matching Difficulty Comparison between FT and CP
- How to Find Out the Matching Solution by Using Smith Chart
- Bandwidth Comparison between T3 and T5 Matching Circuit
- Verification Case on T5 and T3
- Conclusion

## • RF Matching Difficulty Comparison between FT and CP

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Band +	Duplex mode <sup>[A 1]</sup> \$	<b>f</b> (MHz) <b>≑</b>	Common name 🔶	Subset of band +	Uplink <sup>[A 2]</sup> (MHz) ▼	Downlink <sup>[A 3]</sup> (MHz) ♦	Duplex spacing (MHz) \$	Channel bandwidths <sup>[5]</sup> (MHz)
n79	TDD	4700	C-Band		440	0 – 5000	N/A	40, 50, 60, 80, 100
n78	TDD	3500	S-Band	n77	330	0 – 3800	N/A	10, 20, 40, 50, 60, 80, 100

TDD	3700	S-Band	3300 – 4200	N/A	10, 20, 40, 50, 60, 80, 100	

For 5G sub-6GHz application, its bandwidth should be over 900MHz, so the wideband matching is imperative for L/B.

Wider bandwidth for 5G is needed.

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Rand A	Duplex	f .	Common	Subset of band	Uplink	Downlink	Duplex spacing	Channel bandwidths
Banu y	mode <sup>[A 1]</sup> *	(MHz)	name	Subset of ballor \$	(MHz)	(MHz)	(MHz)	(MHz)
47	TDD	5900	U-NII-4 <sup>[A 16]</sup>		5855 -	- 5925	N/A	10, 20
46	TDD	5200	U-NII <sup>[A 15]</sup>		5150 -	- 5925	N/A	10, 20
43	TDD	3700	C-Band		3600 -	- 3800	N/A	5, 10, 15, 20
48	TDD	3500	CBRS (US)		3550 -	- 3700	N/A	5, 10, 15, 20
49	TDD	3500	C-Band	48	3550 -	- 3700	N/A	10, 20
22	FDD	3500	C-Band		3410 – 3490	3510 - 3590	100	5, 10, 15, 20
42	TDD	3500	CBRS (EU, Japan)		3400 -	- 3600	N/A	5, 10, 15, 20
52	TDD	3300	C-Band		3300 -	- 3400	N/A	5, 10, 15, 20
38	TDD	2600	IMT-E <sup>[A 14]</sup>	41	2570 -	- 2620	N/A	5, 10, 15, 20
7	FDD	2600	IMT-E		2500 – 2570	2620 - 2690	120	5, 10, 15, 20
41	TDD	2500	BRS	7	2496 -	- 2690	N/A	5, 10, 15, 20
53	TDD	2400	S-Band		2483.5	- 2495	N/A	1.4, 3, 5, 10
				-				

4G LTE bandwidth is less than 5G.

#### RF Matching on <u>CP</u>:

• No room inside the probers to let engineers hook instrument cable up to Probe Card closely.



## RF Matching on <u>FT</u>:

• Engineers can rely on VNA and move it closer to ATE for RF Matching.



#### For CP RF Matching:

- Engineers can only measure the power(dBm) from ATE program, and couldn't further to use instrument.
- It will let RF matching become difficult when signal path contains many impedance discontinuity interfaces, Normally, engineers can only do Try-and-Error tuning on the space transformer of the probe card.



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- RF Matching Difficulty Comparison between FT and CP For CP RF Matching:
  - It will take 1 hour or a little bit longer when soldering one component from the space transformer of the probe card and then re-docking probe card onto the prober roughly.
  - Engineers probably force the component pads to peel off from the PCB after multiple soldering.



## How to Find Out the Matching Solution by Using Smith Chart



We can closely estimate the input impedance of the DUT after soldering series components R, L, and C sequentially on the matching network and getting three separate power levels from the TX power or RX strength of ATE datalog.



# Bandwidth Comparison Between T5 and T3 Matching Circuit

T5 RF matching network is much preferred because its wider bandwidth matching can conquer some uncertain factors than T3.

Such as:

- 1. wider bandwidth
- 2. better linearity
- 3. wider testing temperature range
- 4. more tolerance is allowable of overused solder on the component pad

5. more L, C variation is allowable for multi-site projects

1. wider bandwidth

S11	BW, S11<-10dB
T5	2.07GHz
Т3	0.85GHz



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- Bandwidth Comparison between T3 and T5 Matching Circuit
  - 2. better linearity

S21	BW, ∆S21<-1dB, Fc=3.75GHz
T5	2.42GHz
Т3	1.09GHz



#### 3. wider testing temperature range

S11	25°C	100°C	Difference
T5	2.07GHz	1.93GHz	6.76%
T3	0.85GHz	0.772GHz	9.17%





4. more tolerance is allowable of overused solder on the component pad



S11	Origin	Overuse Solder	Difference
T5	2.07GHz	2.05GHz	2.38%
Т3	0.85GHz	0.74GHz	12.9%





5. more L, C variation allowable on multi-site projects

S11	Origin	Component Variation (Value - 10%)	Differenc e
T5	2.07GHz	1.93GHz	6.76%
T3	0.85GHz	0.75GHz	11.76%





• Verification Case on T5 and T3

#### 3 Advantages:

1. Easy to match to 50ohm (Shorter time for matching)

2. Cover the variation of component value variation (Stable for Multi-site)

3. Better S11 with flatter S21 for the whole channel. (Channel flatness)



#### Conclusion

◆ For CP testing, engineers usually do Try-and-Error tuning on the space transformer of the probe card and peel off the component pad from the PCB through multiple soldering.

◆ CHPT RF Matching Tool can come up with the best T5 or T3 RF matching component after series R, L, C respectively and measure the power(dBm) from ATE program.

- ◆ 5 advantages of T5 Circuit than T3:
- 1. Wider Bandwidth(shorter time for matching).
- 2. Better insertion loss linearity.(better channel flatness)
- 3. Wider testing temperature range.
- 4. More tolerance is allowable of overused solder on the component pad.
- 5. More L, C variation is allowable on multi-site projects.(multi-site is stable).
- According to the verification results from customers, the bandwidth of T5 matching circuit is wider than T3.



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